

# SPECIFICATION

**Device Name** : IGBT Module  
**Type Name** : 1MB1600PX - 120 - 01  
**Spec. No.** : MS5F4405

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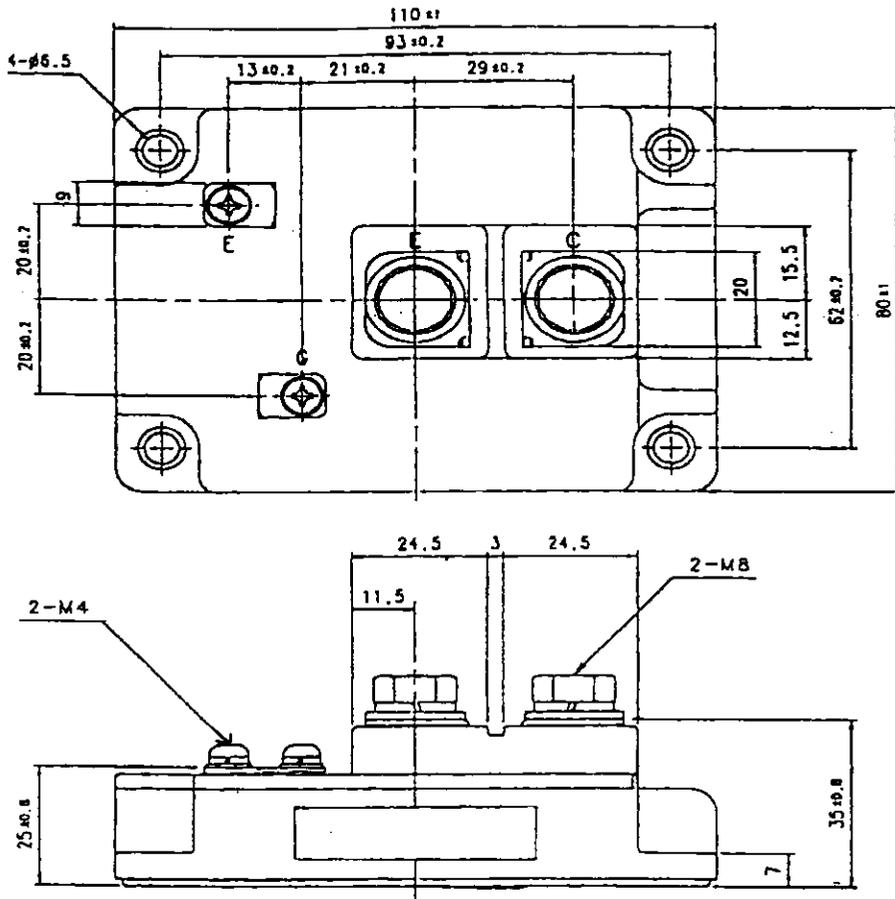
Fuji Electric Co., Ltd.  
 Matsumoto Factory

	DATE	NAME	APPROVED	<b>Fuji Electric Co., Ltd.</b>	
DRAWN	Sep. 9, '98	S. Tashiro	T. HOSEKI	MS5F4405	1/8
CHECKED	Sep. 9, '98	S. Miyata			

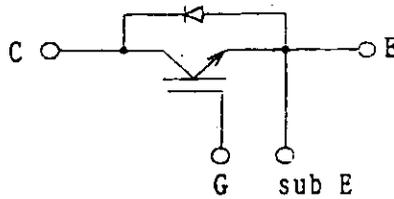


1MBI600PX-120-01

1. Outline Drawing  
Unit : mm



2. Equivalent circuit



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3. Absolute Maximum Ratings ( at Tc=25°C unless otherwise specified )

Items		Symbols	Ratings	Units
Collector-Emitter voltage		V <sub>CEs</sub>	1200	V
Gate-Emitter voltage		V <sub>GEs</sub>	±20	V
Collector current	Continuous	Tc=25°C	I <sub>c</sub>	800
		Tc=80°C		600
	1ms	Tc=25°C	I <sub>c</sub> pulse	1600
		Tc=80°C		1200
			-I <sub>c</sub>	600
	1ms		-I <sub>c</sub> pulse	1200
Max. power dissipation		P <sub>C</sub>	4100	W
Operating temperature		T <sub>j</sub>	+150	°C
Storage temperature		T <sub>stg</sub>	-40~+125	°C
Isolation voltage		V <sub>is</sub>	AC 2500 (1min.)	V
Screw torque		Mounting #1	4.5	N·m
		Terminals #2	11.0	
		Terminals #3	1.7	

Note : #1 Recommendable value : 4.0±0.5 N·m (M6)

Note : #2 Recommendable value : 10.0±1.0 N·m (M8)

Note : #3 Recommendable value : 1.50±0.2 N·m (M4)

4. Electrical characteristics ( at Tj=25°C unless otherwise specified )

Items	Symbols	Characteristics			Conditions	Units
		min.	typ.	max.		
Zero gate voltage Collector current	I <sub>CEs</sub>			2.0	V <sub>GE</sub> =0V, V <sub>CE</sub> =1200V	mA
Gate-Emitter leakage current	I <sub>GES</sub>			±0.5	V <sub>CE</sub> =0V, V <sub>GE</sub> =±20V	μA
Gate-Emitter threshold voltage	V <sub>GE(th)</sub>	6.0	8.0	9.0	V <sub>CE</sub> =20V, I <sub>c</sub> =600mA	V
Collector-Emitter saturation voltage	V <sub>CE(sat)</sub>	2.5	2.85	3.0	V <sub>GE</sub> =15V, I <sub>c</sub> =600A	V
Input capacitance	C <sub>ies</sub>		60		V <sub>GE</sub> =0V	nF
Output capacitance	C <sub>oes</sub>		9		V <sub>CE</sub> =10V	
Reverse transfer capacitance	C <sub>res</sub>		4		f=1MHz	
Turn-on time	t <sub>on</sub>		750	1200	V <sub>CE</sub> =600V	ns
	t <sub>r</sub>		200	600	I <sub>c</sub> =600A	
Turn-off time	t <sub>off</sub>		650	1000	V <sub>CE</sub> =±15V	
	t <sub>f</sub>		100	300	R <sub>G</sub> =2.0Ω	
Diode forward on voltage	V <sub>F</sub>	2.0		3.4	I <sub>F</sub> =600A, V <sub>CE</sub> =0V	V
Reverse recovery time	t <sub>rr</sub>			350	I <sub>F</sub> =600A	ns

5. Thermal resistance characteristics

Items	Symbols	Characteristics			Conditions	Units
		min.	typ.	max.		
Thermal resistance	R <sub>th(j-c)</sub>			0.03	IGBT	°C/W
	R <sub>th(j-c)</sub>			0.06	Diode	
	※		0.0063		the base to cooling fin	
	R <sub>th(c-f)</sub>					

※ This is the value which is defined mounting on the additional cooling fin with thermal compound.

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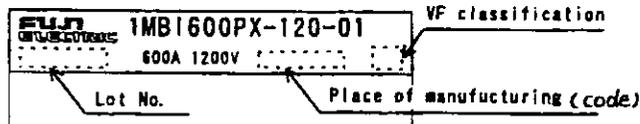
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6. VF class

class	VF range [V]
A	2.0 ~ 2.3
B	2.2 ~ 2.5
C	2.4 ~ 2.7
D	2.6 ~ 3.0
E	2.9 ~ 3.4

7. Indication module (モジュール表示)



8. Applicable category (適用範囲)

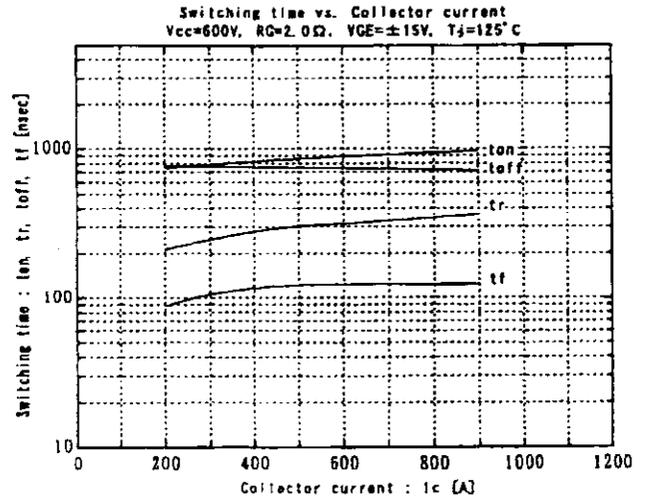
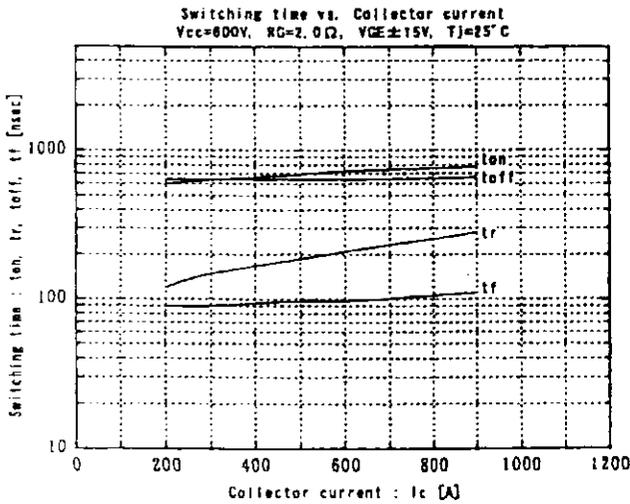
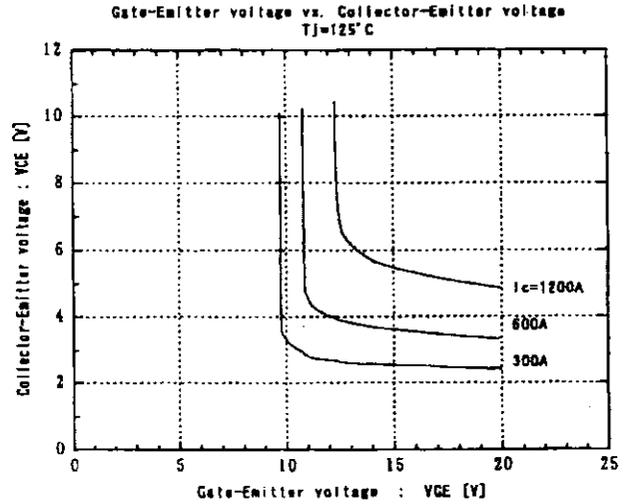
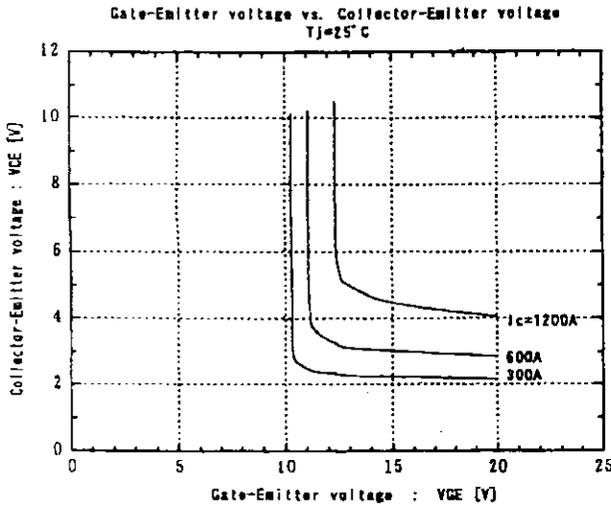
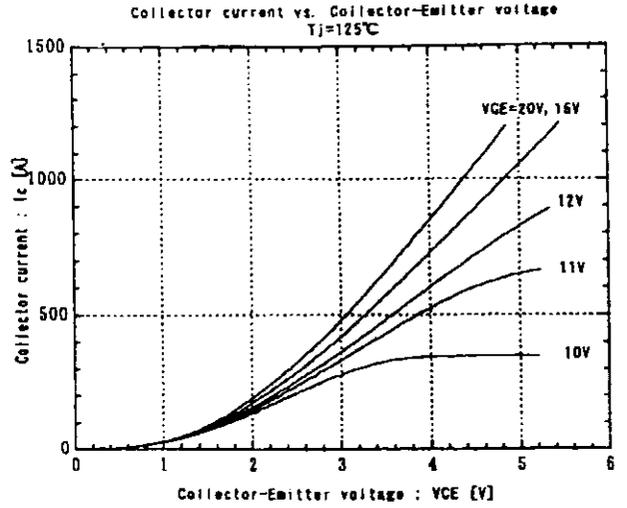
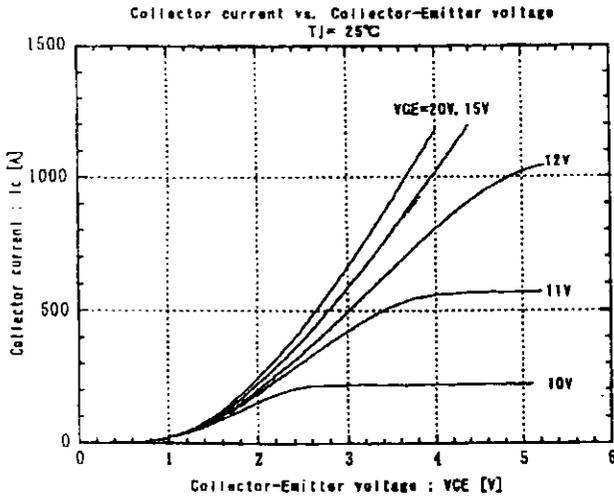
This specification is applied to IGBT module named IMBI600PX-120-01.  
 本納入仕様書は、IGBTモジュール 1MBI600PX-120-01 に適用する。

9. Storage and transportation notes (保管, 運搬上の注意事項)

- This IGBT module should be stored at a standard temperature of 5 to 35°C and humidity of 45% to 75%.  
 常温保存が望ましい。
- Store modules in a place with few temperature changes in order to avoid condensation on the module surface.  
 急激な温度変化の無きこと。(モジュール表面が結露しないこと)
- Avoid exposure to corrosive gases and dust.  
 腐蝕性ガスの発生場所、塵埃の多い場所は避けること。
- Avoid excessive external force on the module.  
 製品に荷重がかからないように十分注意すること。
- Store modules with unprocessed terminals.  
 モジュールの端子は未加工の状態での保管すること。
- Do not drop or otherwise shock the modules when transporting.  
 製品の運搬時に衝撃を与えたり、落下させたりしないこと。

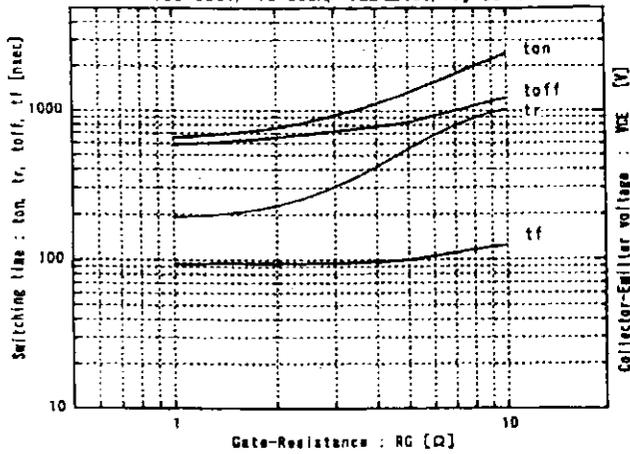
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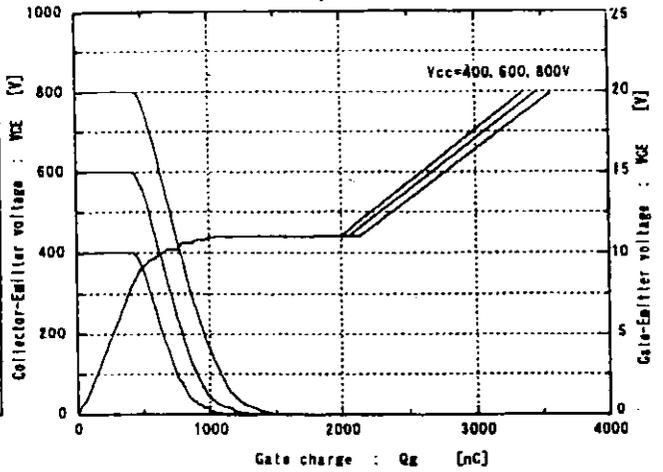


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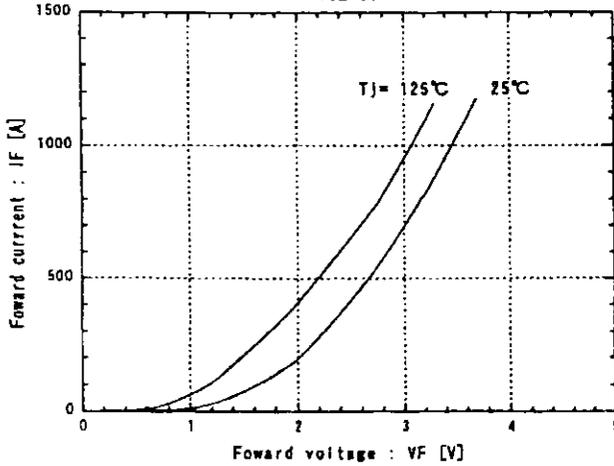
Switching time vs. Gate-Resistance  
 $V_{cc}=600V, I_c=600A, V_{GE} \pm 15V, T_j=25^\circ C$



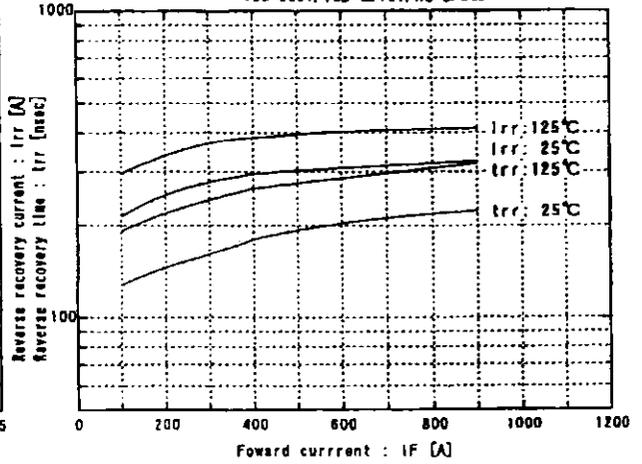
Dynamic input characteristics  
 $T_j=25^\circ C$



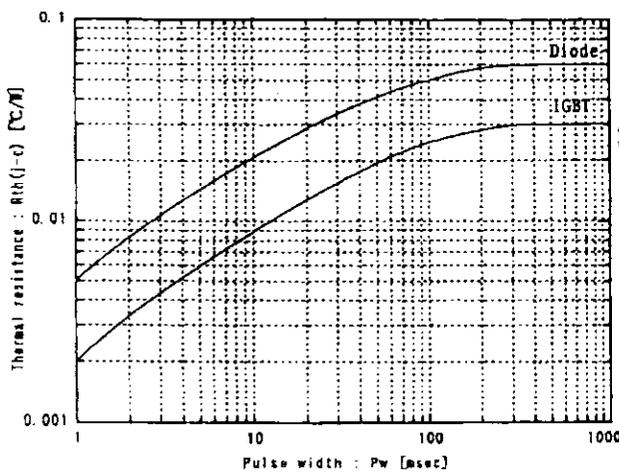
Forward current vs. Forward voltage  
 $V_{GE}=0V$



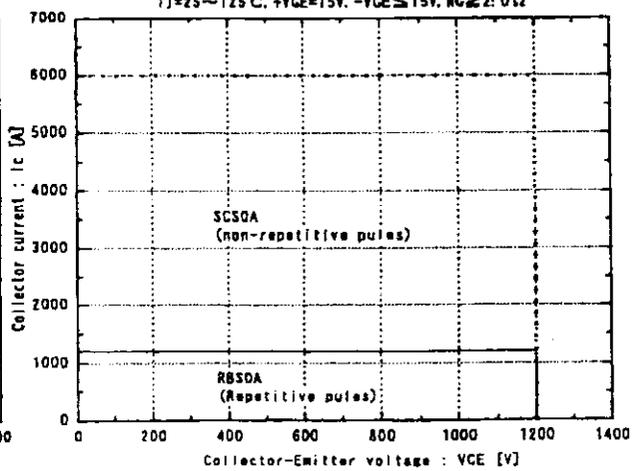
Reverse recovery characteristics ( $t_{rr}, I_{rr}$  vs.  $I_F$ )  
 $V_{cc}=600V, V_{GE} \pm 15V, R_G=2.0\Omega$



Transient thermal resistance



Reverse biased safety operating area  
 $T_j=25\sim 125^\circ C, +V_{GE}=15V, -V_{GE} \le 15V, R_G \ge 2.0\Omega$



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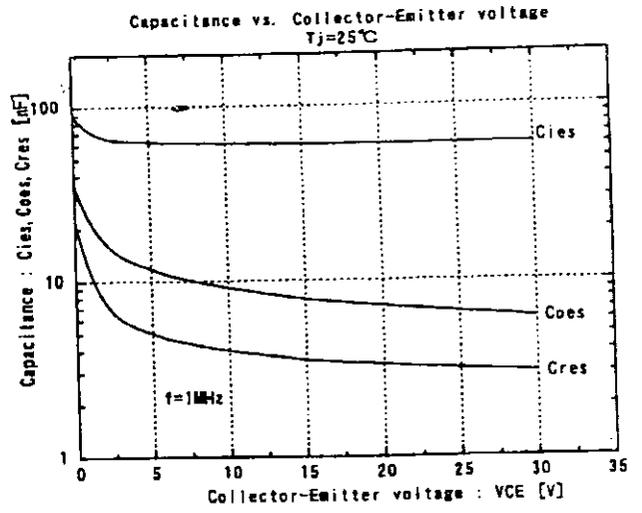
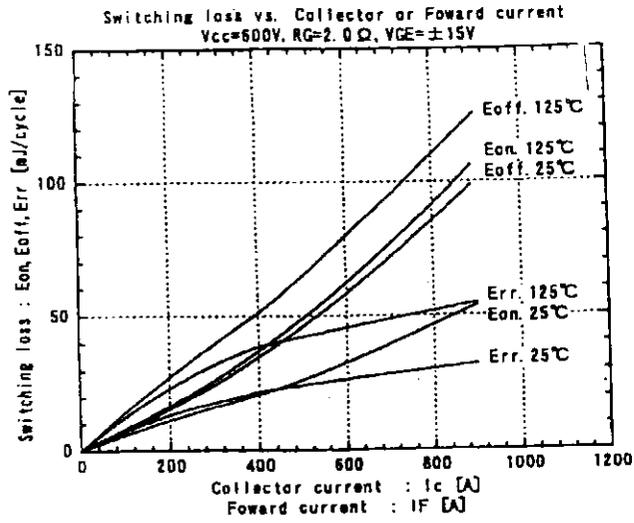
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